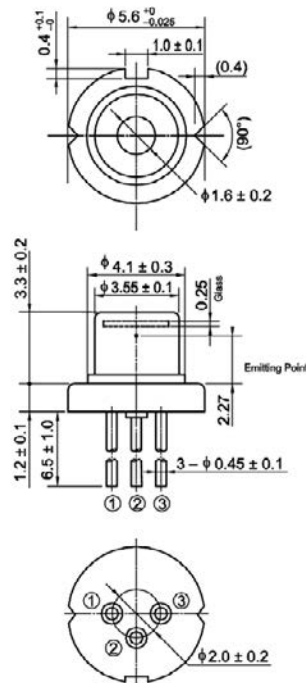


Data Sheet

HL63133DG

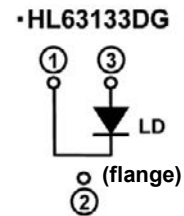
638nm / 170mW AlGaInP Laser Diode

Outline



(unit:mm)

Internal Circuit



Features

- Visible light output: 638nm Typ.
- Optical output power: 170mW (CW)
- Single transverse mode
- Low operating current: 250mA Typ.
- Low operating voltage: 2.8V Typ.
- Small package: $\phi 5.6$ mm
- TE mode oscillation

Application

- Pico projector
- Show laser
- Light source of optical equipments

Absolute Maximum Ratings (Tc=25°C)

Item	Symbol	Ratings	Unit
Optical output power	P _o	170	mW
LD Reverse Voltage	V _{R(LD)}	2	V
Operating Temperature	T _{opr}	-10 ~ +40	°C
Storage Temperature	T _{stg}	-40 ~ +85	°C

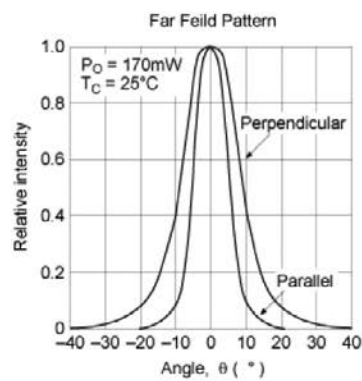
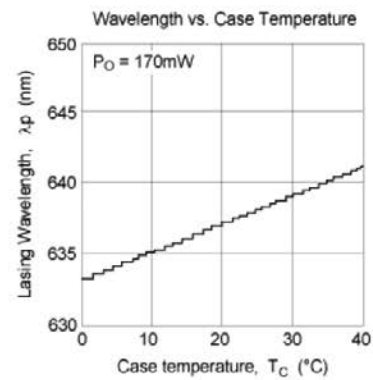
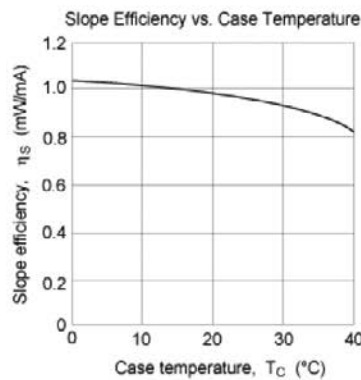
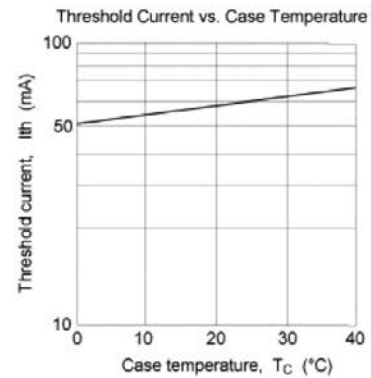
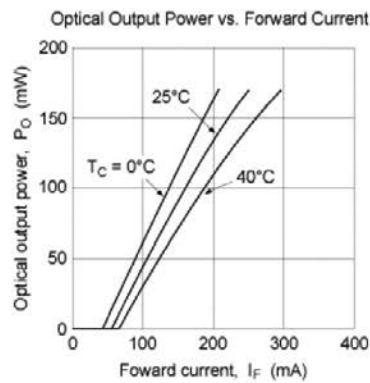
Note: Operating temperature is defined by Case temperature "Tc". High increase in temperature of LD chip itself is expected during operation due to high current density. Thus, without proper heat dissipation, it is observed that no specific output power is achieved or it results to LD degradation. It is advised that sufficient measure of heat dissipation should be taken so that LD's maximum operating temperature is not exceeded during actual operation.

Optical and Electrical Characteristics (Tc=25°C)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Threshold current	I _{th}	-	60	90	mA	-
Operating current	I _{op}	-	250	320	mA	P _o =170mW
Operating voltage	V _{op}	-	2.8	3.2	V	P _o =170mW
Beam divergence Parallel to the junction	θ _{//}	5	9	13	°	P _o =170mW, FWHM
Beam divergence Perpendicular to the junction	θ _⊥	13	17	23	°	P _o =170mW, FWHM
Lasing Wavelength	λ _p	632	638	643	nm	P _o =170mW

Data Sheet HL63133DG Rev0. Oct. 28. 2014

Typical Characteristic Curves



Data Sheet HL63133DG Rev0. Oct. 28. 2014

Cautions

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- 2.This product (without violet laser diode) contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product. When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.

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Data Sheet HL63133DG Rev0. Oct. 28. 2014